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The electronic properties of van der Waals heterostructures can be markedly different from that of the component layers due to the interaction between them. This interaction can be tuned by modifying the interlayer distance, which can be realised by the application of hydrostatic pressure. This can be considered as a new experimental knob to engineer the band structure of such heterostructures. However, the experimental realisation of transport measurements on van der Waals heterostructures under hydrostatic pressure is challenging.

Here, I present a robust measurement method to conduct such measurements based on a designer printed circuit board, which is compatible with wire-bonding [1]. I also demonstrate, using weak localisation measurements, that the applied pressure can enhance the proximity-induced spin-orbit interaction in a graphene/WSe₂ heterostructure [2].

References

- [1] B. Fülöp et al., Journal of Appl. Phys., 130 (2021), 064303
- [2] B. Fülöp, A. Márffy, S. Zihlmann, M. Gmitra, E. Tóvári, B. Szentpéteri, M. Kedves, K. Watanabe, T. Taniguchi, J. Fabian, C. Schönenberger, P. Makk, Sz. Csonka, npj 2D Materials and Applications 5 (2021), 82